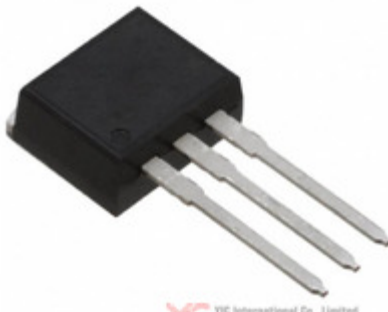

	<h2 style="color: red;">FQI19N20TU</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQI19N20TU
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 200V 19.4A I2PAK
	Datenblätter:  FQI19N20TU.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 950 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQI19N20TU
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 200V 19.4A I2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	950 pcs Stock
detaillierte Beschreibung	N-Channel 200V 19.4A (Tc) 3.13W (Ta), 140W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-262-3 Long Leads, I ² Pak, TO-262AA
Supplier Device-Gehäuse	I2PAK (TO-262)
Verlustleistung (max)	3.13W (Ta), 140W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (V _{dss})	200V
Strom - Ununterbrochener Abfluss (I _d) bei 25 ° C	19.4A (Tc)
R _{ds On} (Max) @ I _d , V _{gs}	150 mOhm @ 9.7A, 10V
V _{GS} (th) (Max) @ I _d	5V @ 250µA
Gate Charge (Q _g) (Max) @ V _{gs}	40nC @ 10V
Eingabekapazität (C _{iss}) (Max) @ V _{ds}	1600pF @ 25V
Antriebsspannung (Max R _{ds On} , Min R _{ds On})	10V
V _{gs} (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQI19N20TU ist neu im Original, Suche FQI19N20TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQI19N20TU AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQI19N20TU: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQI1P50TU Fairchild/ON Semiconductor MOSFET P-CH 500V 1.5A I2PAK</p>	 <p>FQI19N10LTU FSC FQI19N10LTU FSC</p>	 <p>FQI19N20 FSC FSC TO-262</p>	 <p>FQI1P50TU AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 1.5A I2PAK</p>
 <p>FQI27N25TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 25.5A I2PAK</p>	 <p>FQI19N20TU Fairchild/ON Semiconductor MOSFET N-CH 200V 19.4A I2PAK</p>	 <p>FQI19N20CTU AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19A I2PAK</p>	 <p>FQI27N25TU Fairchild/ON Semiconductor MOSFET N-CH 250V 25.5A I2PAK</p>

heiße Teile

Mehr

 FQI10N20CTU	 FQI10N20CTU	 FQI10N20LTU	 FQI11P06TU	 FQI11P06TU
 FQI12N60C	 FQI13N06	 FQI13N06L	 FQI13N50	 FQI13N50C
 FQI13N50CTU	 FQI13N50CTU	 FQI16N15TU	 FQI17N08L	 FQI17P06TU
 FQI17P06TU	 FQI17P20	 FQI19N10LTU	 FQI19N20TU	 FQI27N25TU
 FQI27N25TU	 FQI2N50TU	 FQI2NA90	 FQI2P25TU	 FQI2P25TU
 FQI3N25TU	 FQI3N25TU	 FQI3N30TU	 FQI3N30TU	 FQI47P06TU
 FQI47P06TU	 FQI4N20TU	 FQI4N20TU	 FQI4N80TU	 FQI4N80TU
 FQI4N90TU	 FQI4N90TU	 FQI50N06	 FQI50N06L	 FQI5N20L
 FQI5N50CTU	 FQI5N50CTU	 FQI5N50TU	 FQI5N60C	 FQI5N60CTU
 FQI5N60CTU	 FQI5N60TU	 FQI6N25TU	 FQI6N40TU	 FQI6N60C

Contact us: Info@Y-IC.com

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